



TVS Diodes Transient Voltage Suppression Diodes

SACB Series





Description

SACB series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

Applications

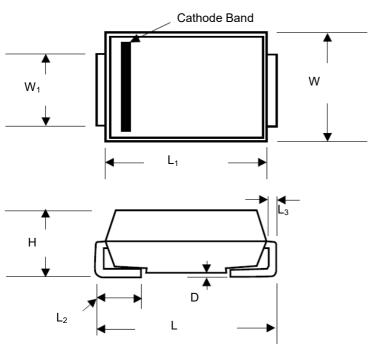
- Communication Equipment
- Security & Protection
- Industrial Control Equipment
- Power Supply
- Automotive Electronics
- New Energy
- Lightning Protection

Features

- 500 W peak pulse capability at 10/1000 μs waveform, repetition rate (duty cycles):0.01%
- For surface mounted applications in order to optimize board space
- Low profile package
- Built-in strain relief
- Typical failure mode is short from over-specified voltage or current
- Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- IEC-61000-4-2 ESD 30 kV (Air), 30 kV (Contact)
- ESD protection of data lines in accordance with IEC 61000
- EFT protection of data lines in accordance with IEC 61000-
- V_{BR} @ T_J= V_{BR}@25 °C x (1+αT x (T_J 25)) (αT:Temperature Coefficient, typical value is 0.1%)
- Glass passivated chip junction
- Fast response time: typically less than 1.0 PS from 0 V to BV min
- Excellent clamping capability
- Low incremental surge resistance
- High temperature reflow soldering guaranteed: 260 °C /
- Plastic package is flammability rated V-0 per Underwriters Laboratories
- Meet MSL level1, per J-STD-020
- Matte tin lead-free plated
- Halogen free and RoHS compliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/JEDEC J-STD-609A.01)

Transient Voltage Suppression Diodes

Package Outline Dimensions (DO-214AA)



	Millime	eters	Inches				
Symbol	Min.	Max.	Min.	Max.			
W ₁	1.95	2.20	0.077	0.086			
L ₁	4.06	4.57	0.160	0.180			
W	3.30	3.94	0.130	0.155			
Н	2.13	2.44	0.084	0.096			
L ₂	0.76	1.52	0.030	0.060			
D	-	0.203	-	0.008			
L	5.21	5.59	0.205	0.220			
L ₃	0.152	0.305	0.006	0.012			

DO-214AA (SMB J-Bend)

Maximum Ratings and Characteristics

(T_A = 25 °C unless otherwise specified.)

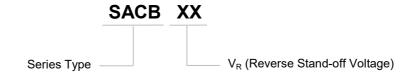
Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at T _L =25 °C by 10/1000 μs Waveform (fig.1)(Note 1)	P _{PPM}	500	W
Power Dissipation on Infinite Heat Sink at T∟=50 °C	P _D	3.0	W
Operating Junction and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C

Notes

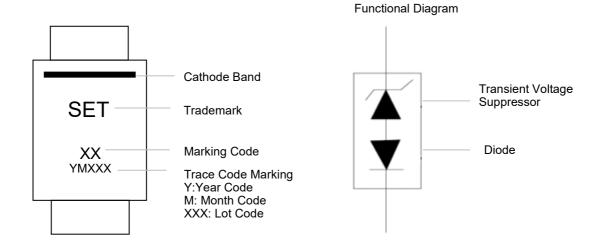
Non-repetitive current pulse, per Fig. 3 and derated above T_J (initial)=25 °C per Fig. 2.

TVS Diodes Transient Voltage Suppression Diodes

Part Numbering System



Marking





Transient Voltage Suppression Diodes

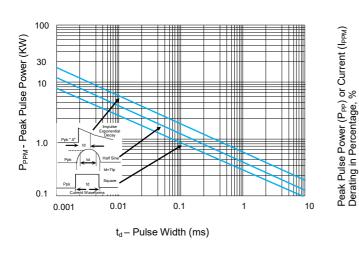
SACB Series

Electrical Characteristics (T_A=25 °C unless otherwise noted)

Part Number	Device Marking Code	Min. Breakdown Voltage at I₁=1 mA VBR	Reverse Stand-off Voltage V _R	Max. Reverse Leakage I _R @V _R	Max. Peak Pulse Current I _{PPM}	Max. Clamping Voltage at Vշ@I _{₽₽M}	Max. Junction Capacitance @0 Volts	Junction Inverse Blocking		Peak Inverse Blocking Voltage V _{PIB}
Uni	Uni	(V)	(V)	(μΑ)	(A)	(V	(pF)	(V)	(mA)	(V)
SACB5.0	SKE	7.60	5.00	300.00	44.00	10.00	45	75	1.0	100
SACB6.0	SKG	7.90	6.00	300.00	41.00	11.20	45	75	1.0	100
SACB7.0	SKM	8.33	7.00	300.00	38.00	12.60	45	75	1.0	100
SACB8.0	SKR	8.89	8.00	100.00	36.00	13.40	45	75	1.0	100
SACB8.5	SKT	9.44	8.50	50.00	34.00	14.00	45	75	1.0	100
SACB10	SKX	11.10	10.00	5.00	29.00	16.30	45	75	1.0	100
SACB12	SLE	13.30	12.00	5.00	25.00	19.00	45	75	1.0	100
SACB15	SLM	16.70	15.00	5.00	20.00	23.60	45	75	1.0	100
SACB18	SLT	20.00	18.00	5.00	15.00	28.80	45	75	1.0	100
SACB22	SLX	24.40	22.00	5.00	14.00	35.40	45	75	1.0	100
SACB26	SME	28.90	26.00	5.00	11.10	42.30	45	75	1.0	100
SACB30	SMK	33.30	30.00	5.00	10.00	48.60	45	75	1.0	100
SACB36	SMP	40.00	36.00	5.00	8.60	60.00	45	75	1.0	100
SACB45	SMV	50.00	45.00	5.00	6.80	77.00	45	150	1.0	200
SACB50	SMZ	55.50	50.00	5.00	5.80	88.00	45	150	1.0	200

Transient Voltage Suppression Diodes

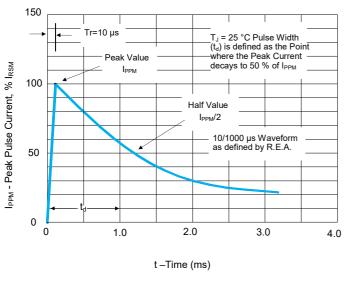
Performance Curve for Reference(T_A=25 °C unless otherwise noted)



100 80 60 40 20 0 25 50 75 100 125 150 175 T_J –Initial Junction Temperature (°C)

FIGURE 1 Peak Pulse Power Rating Curve

FIGURE 2 Peak Pulse Power Derating Curve



Low Capacitance

Application Note: Device must be used with two

FIGURE 3 Pulse Waveform

units in parallel, opposite in polarity as shown on circuit for AC signal line protection.

FIGURE 4 AC Line Protection Application

Environmental Specifications

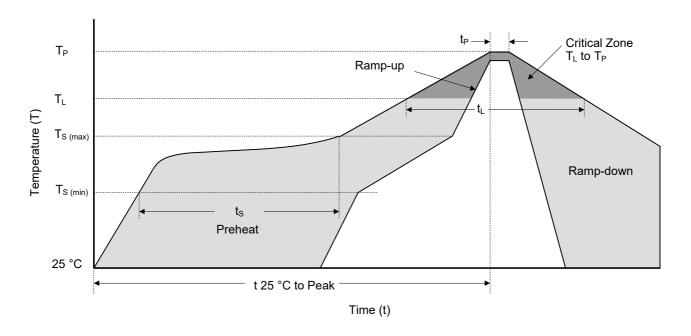
High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Temperature Cycling	JESD22-A104
MSL	JEDEC-J-STD-020, Level 1
H3TRB	JESD22-A101
RSH	JESD22-A111

Physical Specifications

Weight	0.003 oz., 0.093 g
Case	JEDEC DO-214AA molded plastic body over glass passivated junction.
Polarity	Color band denotes cathode except Bidirectional
Terminal	Matte Tin-plated leads. Solderable per JESD22-B102.



Soldering Parameters



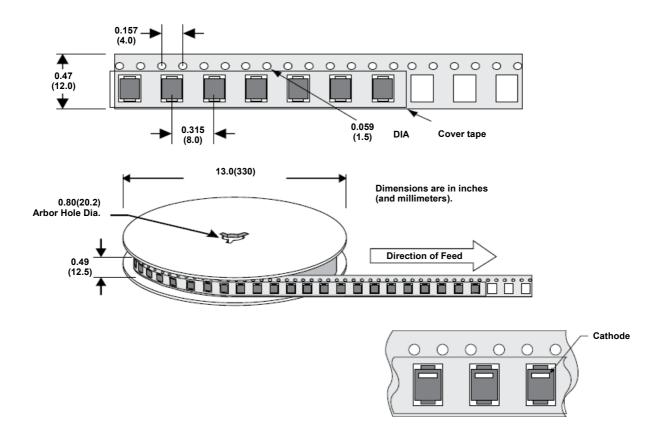
Reflowing Condition

Reflow Soldering	Reflow Soldering Parameters							
	Temperature Min (T _{S (min)})	150 °C						
Pre-heat	Temperature Max (T _{S (max)})	200 °C						
	Time (min to max) (t _s)	60 ~ 120 seconds						
Average Ramp Up Rate (L	3 °C / second max.							
T _S (max) to T _L	Ramp-up Rate	3 °C / second max.						
D. 6	Temperature (T _L) (Liquidus)	217 °C						
Reflow	Time (min to max) (t _L)	60 ~ 150 seconds						
Peak Tempo	erature (T _P)	260 ^{+0/-5} °C						
Time of within 5 °C of Acti	ual Peak Temperature (t _P)	20 ~ 40 seconds						
Ramp-do	own Rate	6 °C / second max.						
Time from 25 °C to	Time from 25 °C to Peak Temperature							
Do Not	Do Not Exceed							

Flow/Wave Soldering (Solder Dipping)

Peak Temperature	260 °C+0 /- 5 °C
Dipping Time	10 seconds
Soldering Number	1 time

Packaging Information



Part Number	Package	QTY (Reel)	Packaging Option	Packaging Specification
SACBXX	DO-214AA	3000 PCS	Tape & Reel - 12 mm tape/13" reel	EIA RS-481



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Glossary

Item	Description
V _C	Clamping Voltage Voltage across TVS in a region of low differential resistance that serves to limit the voltage across the device terminals.
V _R	Reverse Stand-off Voltage Maximum voltage that can be applied to the TVS without operation. NOTE: It is also shown as V_{WM} (maximum working voltage (maximum d.c. voltage)) and known as rated stand-off voltage (V_{so}).
I _R	Reverse Leakage Current Current measured at $V_{R.}$ NOTE : Also shown as I_{D} for stand-by current.
V _{BR}	Breakdown Voltage Voltage across TVS at a specified current I_T in the breakdown region.
I _{PPM}	Rated Random Recurring Peak Impulse Current Maximum-rated value of random recurring peak impulse current that may be applied to a device.
P _{M(AV)}	Rated Average Power Dissipation Maximum-rated value of power dissipation resulting from all sources, including transients and standby current, averaged over a short period of time.
P _{PPM}	Rated Random Recurring Peak Impulse Power Dissipation Maximum-rated value of the product of rated random recurring peak impulse current (I_{PPM}) multiplies by specified maximum clamping voltage (V_{C}).
CJ	Capacitance Capacitance across the TVS measured at a specified frequency and voltage.
V _{FS}	Peak Forward Surge Voltage Peak voltage across an TVS for a specified forward surge current (I_{FS}) and time duration. NOTE: Also shown as $V_{F.}$
I _{FS}	Forward Surge Current Pulsed current through TVS in the forward conducting region. NOTE : Also shown as $I_{\rm F.}$
α _{V(BR)}	Temperature Coefficient of Breakdown Voltage The change of breakdown voltage divided by the change of temperature.
I PP	Peak pulse Current Peak pulse current value applied across the TVS to determine the clamping voltage $V_{\mathbb{C}}$ for a specified wave shape.
I _T	Pulsed D.C. Test Current Test current for measurement of the breakdown voltage V_{BR} . This is defined by the manufacturer and usually given in milliamperes with a pulse duration of less than 40 ms. NOTE: Also shown as I_{BR} .

--(GB-T 18802.321 / IEC 61643-321 / JESD210A)



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Usage

- TVS must be operated in the specified ambient temp.
- Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
- 3. Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

Replacement

- If TVS is visually damaged, please replace it.
- TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

Storage

- 1. Storage Temp. Range: (-55 to 150) °C.
- Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder- ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

Environmental Conditions

- 1. TVS should not be exposed to the open air, nor direct sunshine.
- 2. TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
- TVS should avoid sand dust, salt mist, or other harmful gases.

Max. Typical Capacitance of TVS

The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

Installation Mechanical Stress

- 1. Do not knock TVS when installing, to avoid mechanical damage.
- 2. Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.

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Transient Voltage Suppression Diodes

Transient Voltage Suppressor (Surface Mount) Features Overview

	1	\								/	\		
	DO-221AC	0	0	0	0	0	SMA6L	0	0	0			
be	DO-214AA	0	0	0	0	0	0	SACB	SMBJ	P6SMB			
Package Type	DO-214AB										Series		
ıckaç	DO-214AC	0	0	SMAJ	P4SMA	SMA6J	0	0	0	0	ies		
Ра	SOD-123FL	SMF	P4SMF										
	SMTO-218	0	0	0	0	0	0	0	0	0			
Proc	duct Outline (mm)	3.65			5.04		5.20 80 7		5.40				
V F Revers	R / V WM (V) e Stand-off Voltage	5.0 ~ 250	5.0 ~ 85	5.0 ~ 440	5.8 ~ 468	5.0 ~	250	5.0 ~ 50	5.0 ~ 440	5.8 ~ 512			
(10 Rate Po	PPM (W) (10/1000 µs) Rated Peak ImPulse Power Dissipation		400 600					6	00				
PPM (Rated P	kA)(8/20 µs) eak ImPulse Current					0							
C Te	perating mperature (°C)					-55 to +150							

Transient Voltage Suppressor (Surface Mount) Features Overview

	1									,	^
DC	O-221AC	0	0	0	0	0	0	0	0	0	
e DC	O-214AA	0	0	0	0	0	0	0	0	0	
Package Type	O-214AB	SMCJ	1.5SMC	3.0SMCJ	SMDJ	5.0SMDJ					Series
ckago DO	O-214AC	0	0	0	0	0	0	0	0	0	ies
₽ SOI	D-123FL										
SN	MTO-218	0	0	0	0	0	SPC1	SPC3	SPC6	SPC10	
	t Outline nm)			7.94				7.09	3.27		
V _R / V Reverse Star	/ _{WM} (V) ind-off Voltage	5.0 ~ 440	5.8 ~ 512	5.0 ~	- 440	12 ~ 170	380 / 430	66	58 ~ 76	58 ~ 86	
PPPI (10/10 Rated Pea Power Di	PM (W) DOO µS) eak ImPulse Dissipation	15	00	30	100	0					
PPM (KA) Rated Peak In)(8/20 µS) mPulse Current			0		1	3	6	10		
Tempe	rating erature °C)			-55 to +150		-55 to +125					

Transient Voltage Suppressor (Axial Lead) Features Overview

TVS Diodes Transient Voltage Suppression Diodes

	/	\														/	\
	DO-201	0	0	0	1.5KE	LCE	0	0	0	0	0	0	0	0	0	0	
Гуре	DO-41	P4KE															4.
Package Type	DO-15	0	SAC	P6KE	0	0	0	0	0	0	0	0	0	0	0	0	Series
Pack	P600	0					5KP	15KPA	20KPA	30KPA							, ,,
Rad	dial lead	0	0	0	0	0	0	0	0	0	SPCL1	SPCL3	SPCL6	SPCL10	SPCL15	SPCL20	
	t Outline nm)	100 ± 4.65 42.35 1.00 ± 4.65 45 1.00 ± 4.65 1.00 ± 4.	Ф3.10 02 6 Ф0.78	57.50	Φ5.05 • 98. • 61.00	59.15		Ф8.85 	59.65		27.048	17.00	12.70	20.48	14.50	2.00	
V _R / V Reverse Star	WM(V) nd-off Voltage	5.8 ~ 468	5.0 ~ 50	5.8 ~ 512	5.8 ~ 512	6.5 ~ 90	5.0 ~ 250	17 ~ 280	20 ~ 300	28 ~ 360	76	15 ~ 430	30 ~ 430	15 ~ 530	58 ~ 380	16 ~ 76	
PPPI (10/10 Rated Pea Power D	M (W) 100 µs) ak ImPulse issipation	400	500	600	15	00	5000	5000 15000 20000 30000						0			
PPM (KA) Rated Peak In	(8/20 µs) nPulse Current					0					1	3	6	10	15	20	
Tempe	rating erature C)	-55 to +150								·	-55	to +125					